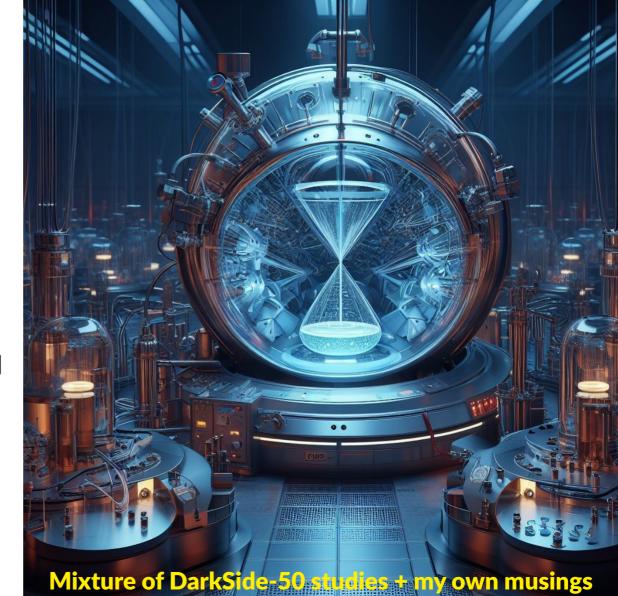
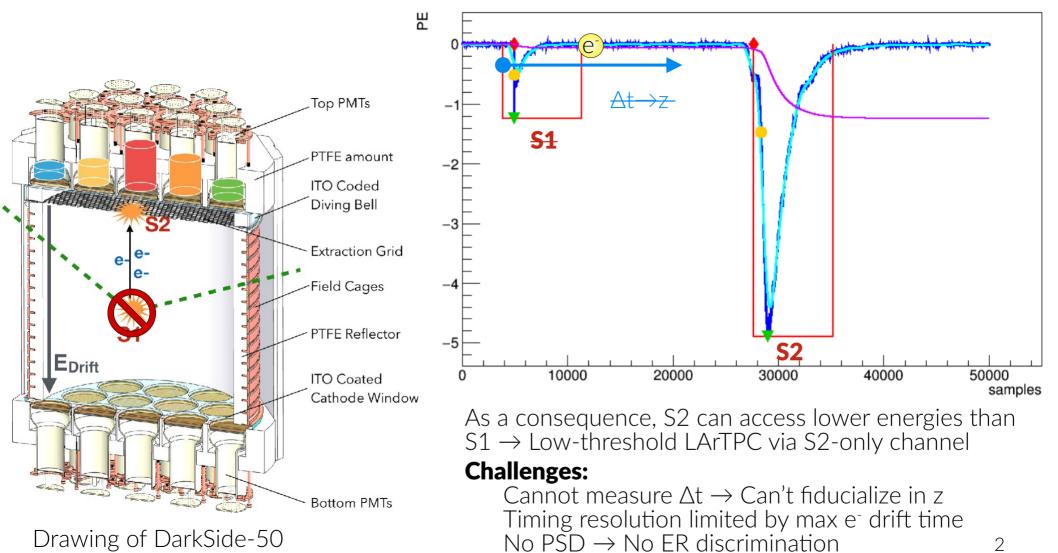
Lowering the threshold of dual-phase LArTPCs

Shawn Westerdale [w/ the Global Argon Dark Matter Collaboration] CPAD : RDC 1 8 November, 2023

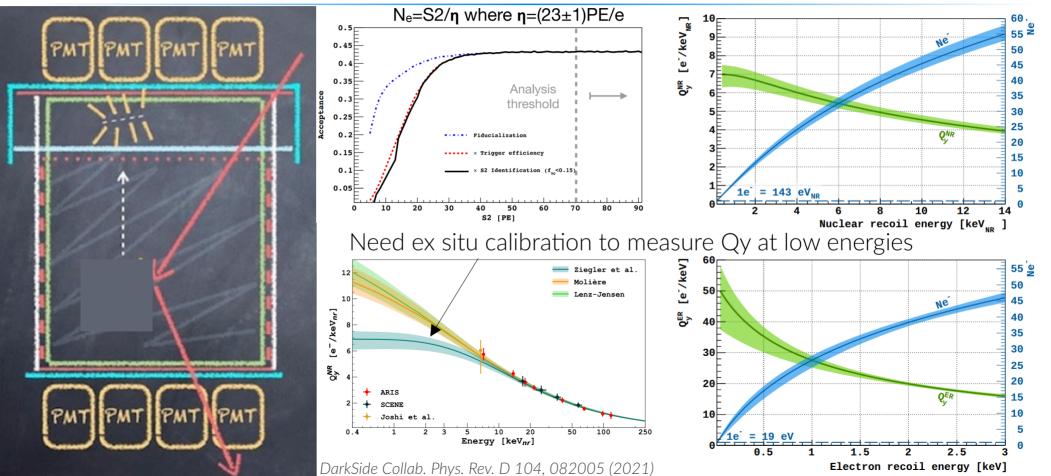
Bing AI, draw a low-threshold time projection chamber



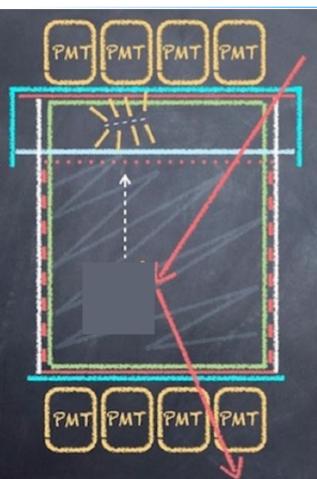


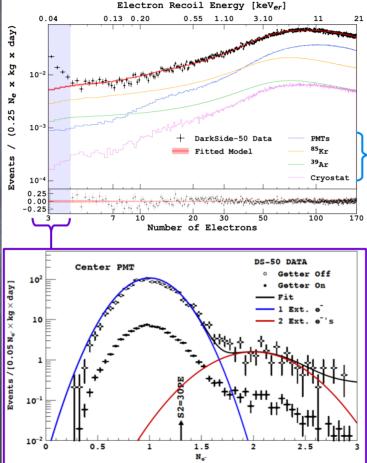
Spurious electron backgrounds

Low-threshold S2-only analyses, but lose PSD and z position reconstruction



Low-threshold S2-only analyses





Loss of pulse shape discrimination (PSD)

Electromagnetic backgrounds from dominate $\gamma\text{-}rays$ from internal radioactivity $\beta\text{-}decays$ from ^{39}Ar and ^{85}Kr

^Use underground/depleted Ar

Spurious e's **dominate lowest energy bins**

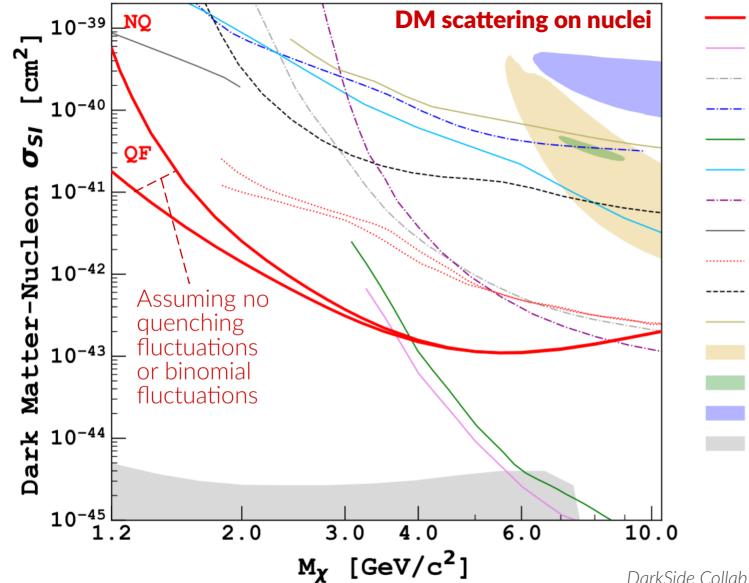
Full origin being investigated

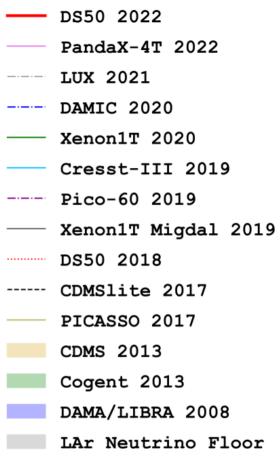
Correlations between SE and preceding S2 (time, xy position, S2 charge and $t_{\rm drift}$ vs. $P_{\rm SE})$

Possibly due to drifting electrons capturing on impurities and forming metastable states Follow preceding S2 by O(5-50 ms)

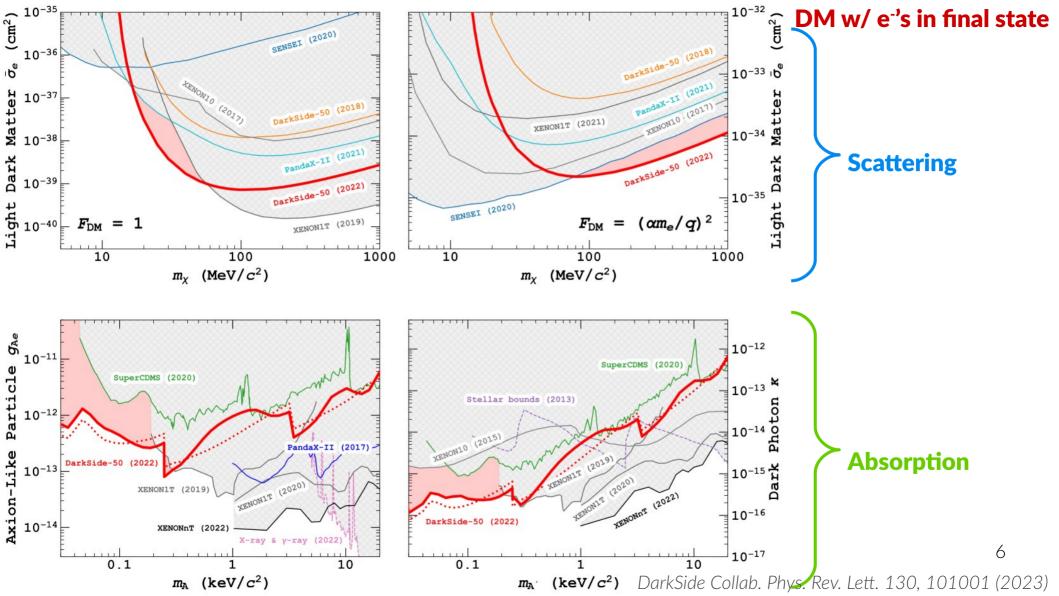
4

DarkSide Collab. Phys. Rev. D 107, 063001 (2023)

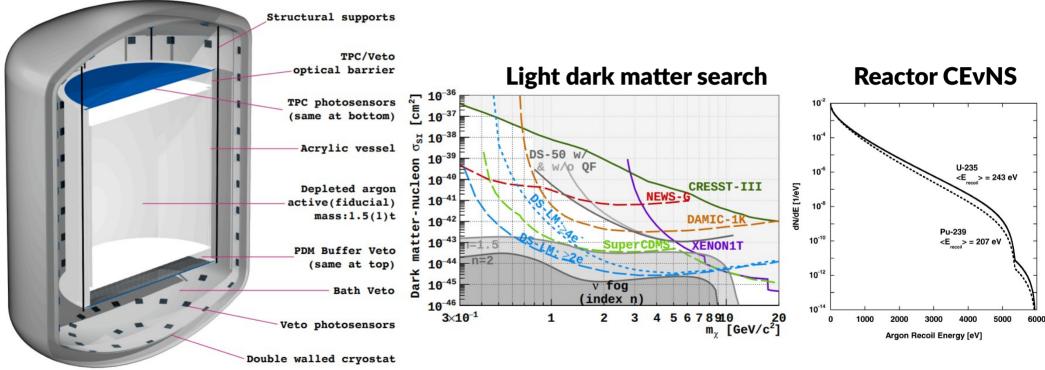




DarkSide Collab. Phys. Rev. D 107, 063001 (2023)



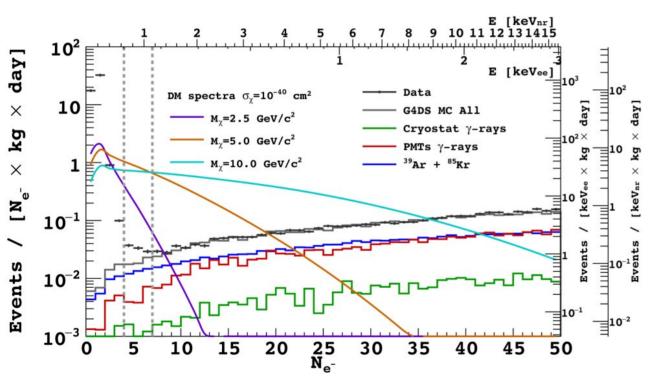
LArTPC in S2-only analyses: Powerful tool for low-threshold measurements



Hagmann & Bernstein, IEEE Trans.Nucl.Sci. 51 (2004) 2151

DarkSide-LowMass conceptual design + sensitivity projections [GADMC Phys. Rev. D 107, 112006]

How do we lower the threshold?



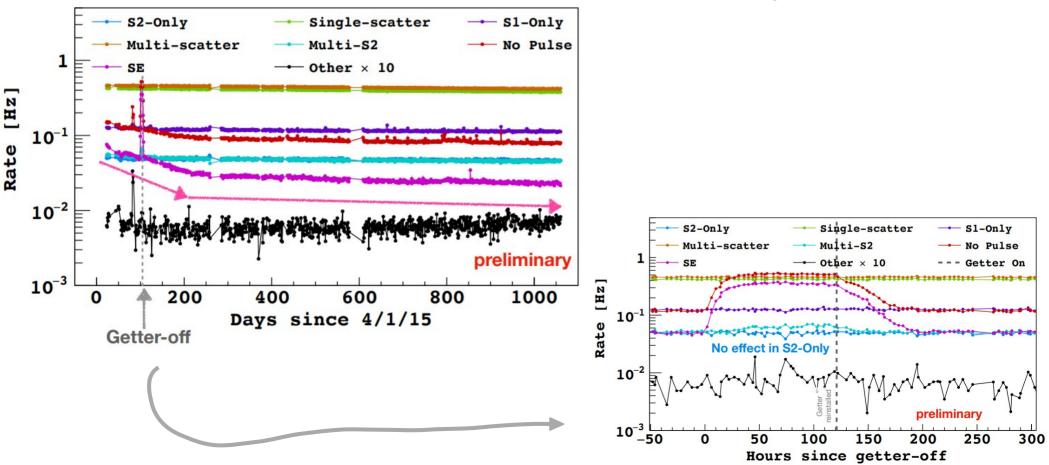
Threshold is set by

Spurious electrons Medium's ionization energy Partitioning between ionization & scintillation photons heat

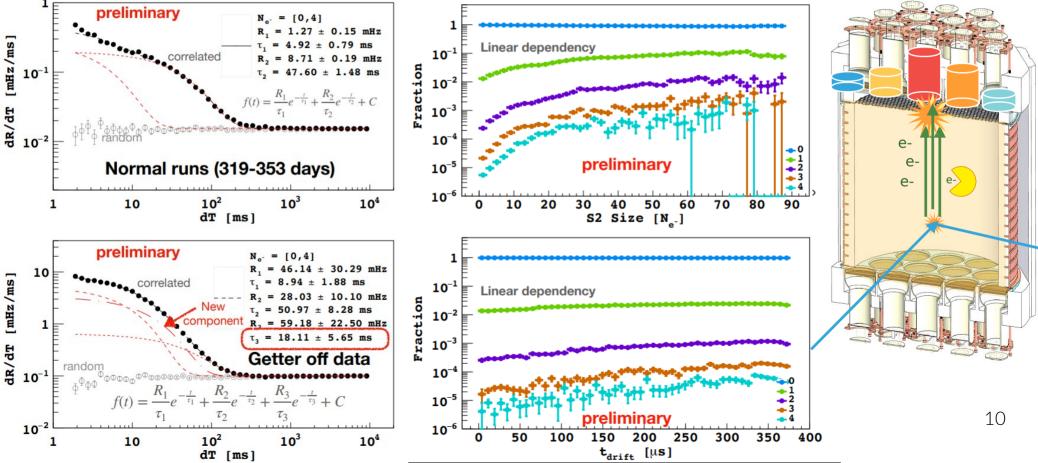
All of these are pathways for lowering the energy threshold

DarkSide Collab. Phys. Rev. Lett. 121, 081307 (2018)

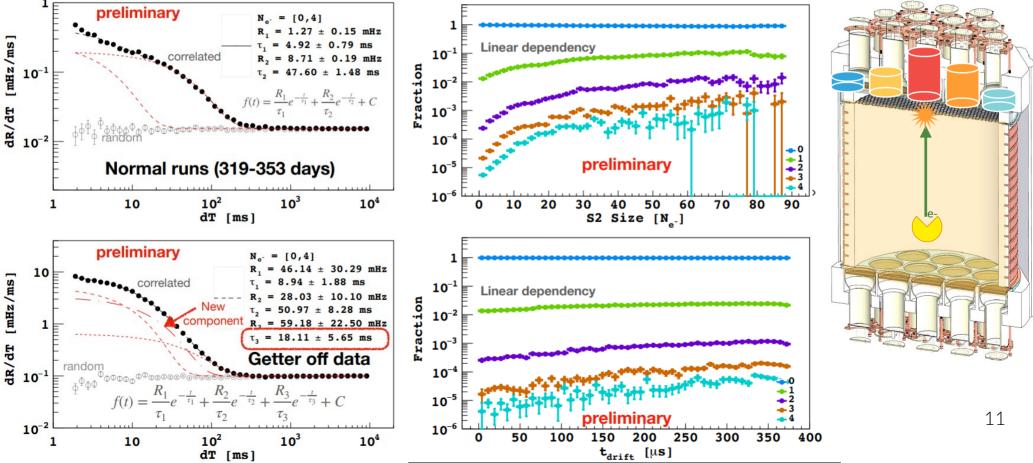
SE rate changes over time and appears to be related to impurities



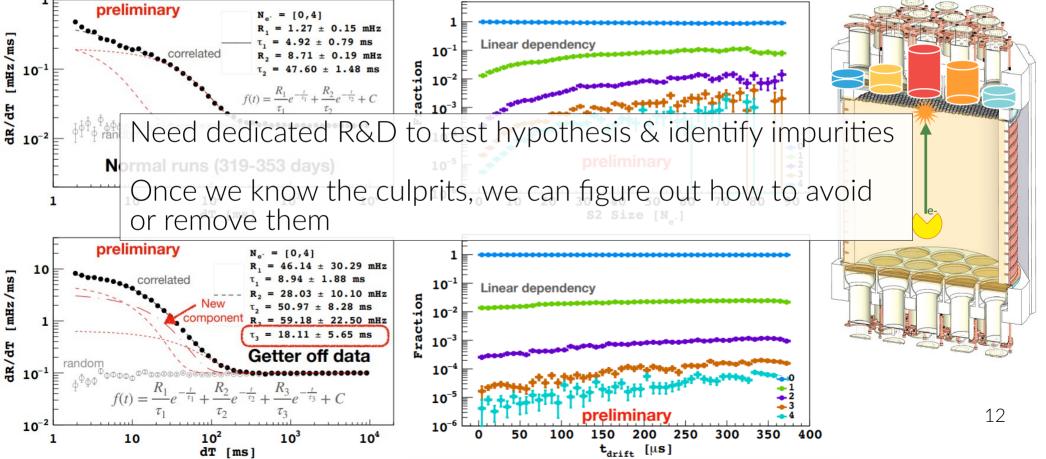
SEs appear to be correlated in time, space, and charge with ordinary events



Hypothesis: Dominant SE production mechanism from impurities trapping e⁻



Hypothesis: Dominant SE production mechanism from impurities trapping e⁻



Other ideas: enhance detector response by doping LAr

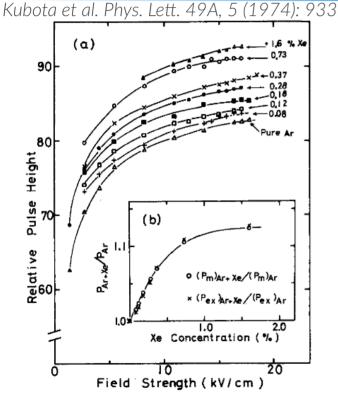


Fig. 1. a) Saturation curves of the pulse height produced by ²⁰⁷Bi conversion electron for the different concentration of Xe. b) Relative ionization yields as a function of doped-Xe concentration.

Idea:

Xe ionization energy is 12.1 eV Ar ionization energy is 15.8 eV, W-value ~ 24 eV Xe-doped LAr effective ionization potential ~ 10.7 eV [B. Raz and J. Jortner, Proc. Roy. Sot. London A 317 (1970) 113.]

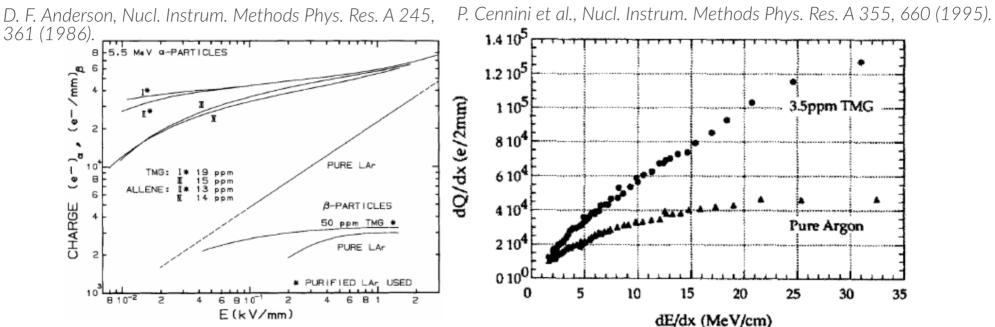
Even at low Xe concentration, each ionization takes less energy from the nucleus, and nuclei can continue to produce ions even down to lower energies

Nuclear recoils produce ionization through a cascade (one nucleus colliding with others, and so on) \rightarrow effects may be non-linear

R&D needs:

Need to measure Qy of low-energy NRs as a function of Xe concentration to see the effect side

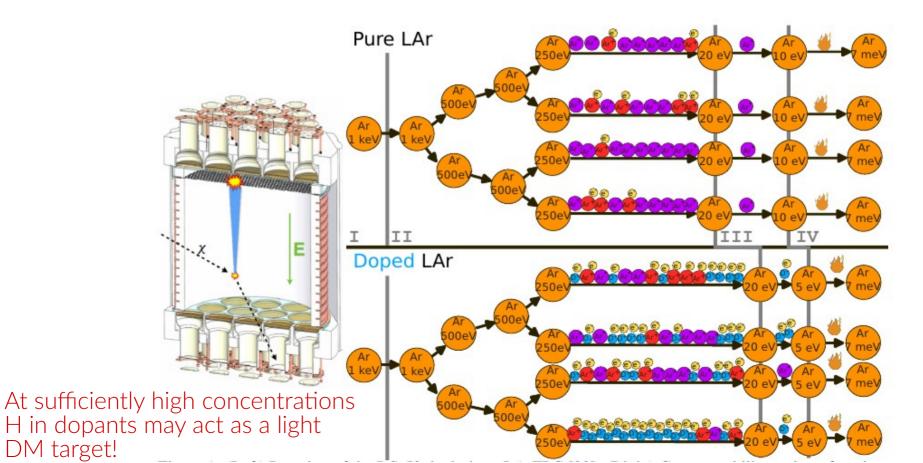
Other ideas: Photo-sensitive dopants potentially great improvements, more R&D



Dopants with 7.5–9.5 eV ionization energies have previously been studied in LAr, in the context of improving the resolution of high-energy ionization chambers

Larger effects at higher ionization energies \rightarrow energy otherwise lost as heat goes into ionization Turns inefficiently detected S1 into efficiently detected S2!

Potential benefits from doping



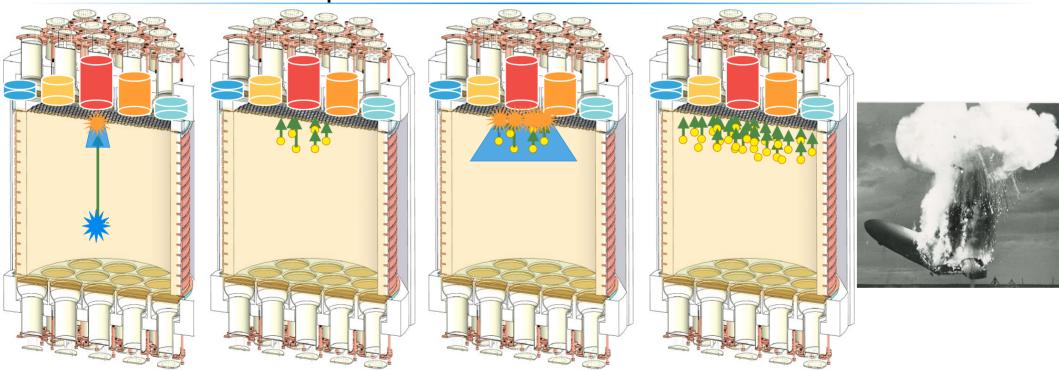
Some potential dopants

Material ^{d)}		I _g [eV] ^{a)}	Dipole moment [debyes] ^{b)}	Estimated pressure 90 K [Torr] ^{b)}	Charge collected* ^{c)} (LAr $\equiv 1$)		Concentration
					$\overline{0.1 \text{ kv mm}^{-1}}$	1.0 kV mm ⁻¹	[ppm]
TEA	$(C_2H_5)_3N$	7.50	0.66	_	2.2	1.3	47
TMA	$(Ch_3)_3N$	7.82	0.612	3×10^{-8}	3.4	1.6	110
TMT	$(CH_3)_4Sn$	8.25/8.76	_	4×10^{-12}	3.0	1.6	1.5
Cyclohexene	$C_{6}H_{10}$	8.95	_	_	2.1	1.3	3.6
1.3-butadiene	C₄H ₆	9.06	0	4×10^{-7}	4.6	1.9	17
Cis & Trans 2 butene	C_4H_8	9.13	0 (trans)	5×10^{-8}	3.6	1.6	72
TMG	(CH ₃) ₄ Ge	9.2/9.29	_	3×10^{-10}	7.4 (9.8)	2.6 (2.7)	15
Isobutylene	C_4H_8	9.23	0.5	5×10^{-7}	4.9	1.8	16
Methyl mercaptan	CH ₃ SH	9.44	1.52	2×10^{-8}	2.0	2.0	15
Pentene (technical)	$C_5 H_{10}$	9.5	_	1×10^{-9}	3.1	1.5	7
Allene	C_3H_4	9.53	0	1×10^{-5}	6.5 (8.7)	2.5 (2.7)	14
TMS	(CH ₃) ₄ Si	9.86	0.525	8×10^{-9}	4.6	1.8	5.8
DME	(CH ₃) ₂ O	10.0	1.30	5×10^{-8}	3.6	1.4	14

D. F. Anderson, NIM. A 245, 361 (1986).

TMG studied by ICARUS, Allene studied by Doke, Hitachi, Masuda, Ichinose, LaVerne et al.

Challenge for photosensitive dopants: S2 feedback



Need to prevent S2 from re-entering liquid or shift S2 to below dopant's ionization energy

R&D needs

Modeling and reducing SEs

Dedicated R&D to identify primary mechanisms Improved chemical purity, likely at the ppb level and better Investigate other subdominant SE production mechanisms

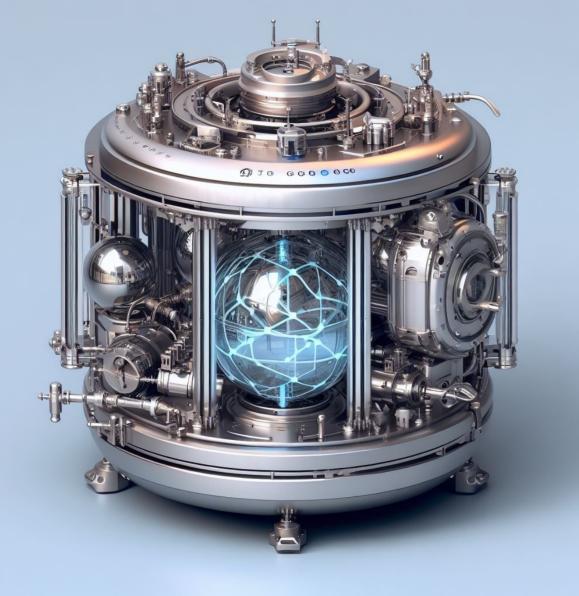
Calibration

Calibrate charge and scintillation yield of low-energy ERs and NRs Need to understand the **fluctuations** about mean yields at low energy

Doping LAr

Calibrate doped LArTPCs to low-energy ERs and NRs vs. dopant concentration

- Develop high-purity doping techniques—need to add dopant w/o adding impurities
- Assess and improve the stability of dopant in LAr
- For photo-sensitive dopants, need to prevent S2 feedback



END